



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Li Docket No.: 2003 P 54557 US  
Serial No.: 10/771,075 Art Unit: 2811  
Filed: February 3, 2004 Examiner: Gene M. Munson  
For: Transistor with Doped Gate Dielectric

**Certificate of Mailing via First Class Mail (37 C.F.R. § 1.8(a))**

Date of Deposit: April 21, 2005

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Respectfully submitted,

Carrie Roth  
Legal Assistant

Slater & Matsil, L.L.P.  
17950 Preston Rd., Suite 1000  
Dallas, TX 75252  
Tel: 972-732-1001  
Fax: 972-732-9218